ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Тур.	Max.	Unit
V_{BR}	T _j = 25°C	$I_R = 100 \mu A$	100			V
V _F *	T _j = 25°C	$I_F = 0.1 \text{mA}$			0.25	V
	$T_j = 25^{\circ}C$	$I_F = 10mA$			0.45	
	T _j = 25°C	I _F = 250mA			1	
I _R *	T _j = 25°C	V _R = 1.5V			0.5	μΑ
	T _j = 60°C				5	
	T _j = 25°C	V _R = 10V			0.8	
	$T_j = 60$ °C				7.5	
	T _j = 25°C	V _R = 50V			2	
	$T_j = 60$ °C				15	
	T _j = 25°C	V _R = 75V			5	
	$T_j = 60$ °C				20	

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Тур.	Max.	Unit
	T _j = 25°C	$V_R = 0V$	f = 1Mhz		10		pF
	T _j = 25°C	$V_R = 1V$	1 - 11/11/2		6		

^{*} Pulse test: $t_p \le 300 \mu s \ \delta < 2\%$.

Fig. 1-1: Forward voltage drop versus forward current (low level, typical values)

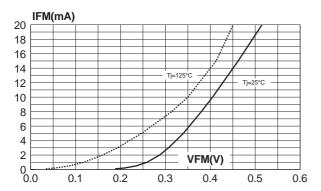


Fig. 1-2: Forward voltage drop versus forward current (high level, typical values)

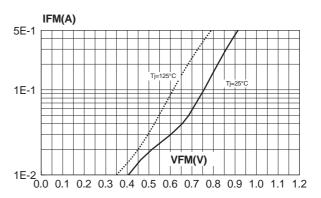


Fig. 2: Leakage current versus reverse voltage applied (typical values)

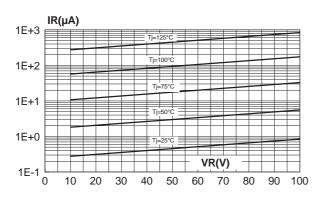


Fig. 3: Leakage current versus junction temperature (typical values)

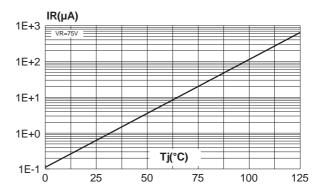
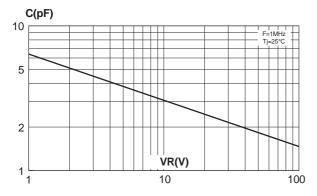


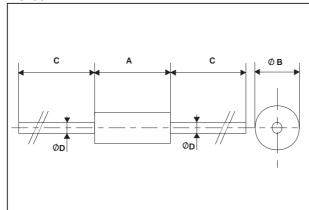
Fig. 4: Junction capacitance versus reverse voltage applied (typical values)



3/4

PACKAGE MECHANICAL DATA

DO-35



REF.	DIMENSIONS				
	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	3.05	4.50	0.120	0.177	
В	1.53	2.00	0.060	0.079	
С	28.00		1.102		
D	0.458	0.558	0.018	0.022	

Cooling method: by convection and conduction

• Marking: clear, ring at cathode end

• Weight: 0.15g

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied.

STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All rights reserved.

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

http://www.st.com

4/4